

Synthesis of linked carbon monolayers: Films, balloons, tubes, and pleated sheets

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Edited by Uwe Bunz, Carnegie Mellon University, and accepted by the Editorial Board March 26, 2008 (received for review October 23, 2007)

Because of their potential for use in advanced electronic, nano-mechanical, and other applications, large two-dimensional, carbon-rich networks have become an important target to the scientific community. Current methods for the synthesis of these materials have many limitations including lack of molecular-level control and poor diversity. Here, we present a method for the synthesis of two-dimensional carbon nanomaterials synthesized by Mo- and Cu-catalyzed cross-linking of alkyne-containing self-assembled monolayers on SiO₂ and Si₃N₄. When deposited and cross-linked on flat surfaces, spheres, cylinders, or textured substrates, monolayers take the form of these templates and retain their structure on template removal. These nanomaterials can also be transferred from surface to surface and suspended over cavities without tearing. This approach to the synthesis of monolayer carbon networks greatly expands the chemistry, morphology, and size of carbon films accessible for analysis and device applications.

networks | nanomaterials | self-assembled

In contrast to carbon nanotubes, fullerenes and various derivatives (1–3), the synthesis of large 2D sheets such as graphene (4), graphyne, and graphdiyne (5, 6) extending over micrometers in lateral dimensions is either in its infancy or has significant limitations. In fact, the synthesis of 2D carbon networks has been recognized as an outstanding challenge in materials chemistry (7).

Graphene, the simplest of the 2D conjugated carbon nanomaterials, is produced by micromechanical cleavage of bulk graphite (HOPG) or by thermal decomposition of silicon carbide (8, 9). However, these approaches lack the molecular-level control necessary to define the chemical makeup of these systems. Scholl coupling reactions on oligophenylene precursors (10) produce small (<15 nm) 2D graphene fragments with improved molecular diversity, and radiation induced modifications of self-assembled (11, 12) or Langmuir–Blodgett (13) monolayers create larger sheets, but with reduced control of the chemistry. Polyelectrolytes (14) represent a different class of chemistry that can form 2D (15) and 3D (16) nanomaterials. These films are formed through deposition of separately synthesized polymers, often in layer-by-layer assemblies, in the form of relatively thick (typically >5 nm) films governed by electrostatic interactions. These limitations, together with those associated with the planar, radiation-cross-linked monolayers, motivate the need for alternative approaches to these classes of materials.

A potential solution to the formation of large 2D conjugated carbon nanomaterials would employ a two-step procedure involving the formation of self-assembled monolayers (SAMs) with highly functionalized monomers followed by chemical cross-linkage of the SAMs to form linked monolayers. Fig. 1 shows the overall process beginning with the formation of SAMs of suitably designed carbon precursors on solid supports, followed by chemical cross-linking to yield covalently bonded networks with monolayer thicknesses. Not only could these materials adopt the geometry of the support, but they could also be transferred by using printing-like techniques to other substrates or lithograph-

ically patterned into desired geometries. This article introduces the use of synthetic organic methods to create linked carbon monolayers and monolayer membranes in forms ranging from planar or structured films and membranes, to spherical coatings, balloons, tubes, and other complex topologies.

Results

Aryl alkynes are attractive monomers for this chemistry because they are a chemically diverse class of molecules that are already highly conjugated, contain primarily carbon by mass, and can be chemically linked through a variety of methods including alkyne metathesis (17), oxidative Cu coupling (18), and Pd-catalyzed cross-coupling (18). Di-functional monomers (**1** and **2**) and a hexa-functional monomer (**3**) were synthesized with triethoxysilyl groups attached by a carbamate group to the aryl core (Fig. 1B) [supporting information (SI) Text]. SiO₂- or Si₃N₄-coated substrates or quartz/glass slides were immersed in monomer solutions (~15 mM monomer, ~10 mM triethylamine, 90–100°C, 24 h, toluene) creating SAMs that exhibited similar advancing contact angles (74–80°) for all three monomers (Table S1). Two different cross-linking chemistries were used to form linked monolayers from these SAMs. Mo(IV)-catalyzed, vacuum-driven alkyne metathesis (17) linked the dipropyne SAMs derived from **1**. Cu-catalyzed Hay-type coupling conditions (18) created linked monolayers from SAMs of monomers **2** and **3**. The advancing contact angles consistently decreased by 6, 11, and 20° for the dipropyne (**1**), diacetylene (**2**), and terphenyl (**3**) chemistries, respectively. After exposing the SAMs to the linkage conditions, it was found that very little residual metal remained on the substrate.

UV-visible (UV-vis) absorption spectra of the SAMs on UV-grade fused quartz closely matched spectral features of the monomers in solution (Fig. S1). The linked monolayer of **1** on quartz possesses a new shoulder at 330 nm (Fig. 2A). Because this new shoulder is small it suggests incomplete polymerization or the formation of oligomers (19, 20). Similarly, the linked monolayer from **2** on quartz possesses a broad new peak at 370 nm (Fig. 2D) that matches the absorbance of poly(1,4-phenylene-1,3-butadienyne) derivatives (20, 21). This has been described as a delocalized $\pi \rightarrow \pi^*$ transition in molecules comprised of multiple 1,4-diphenylbutadiyne chromophores (20). The appearance of these lower-energy peaks suggests an increased delocalization of electrons on oligomerization/polymerization resulting from increased conjugation (21). The spectrum of the linked monolayer of **3** is

Author contributions: M.J.S. and X.Z. contributed equally to this work; M.J.S., X.Z., J.S.M., and J.A.R. designed research; M.J.S., X.Z., S.U., D.-Y.K., Q.C., C.W., and C.L. performed research; X.Z., S.M., J.A.N.T.S., and I.P. contributed new reagents/analytic tools; M.J.S., X.Z., S.U., J.S.M., and J.A.R. analyzed data; and M.J.S., X.Z., J.S.M., and J.A.R. wrote the paper.

Conflict of interest statement: A patent has been filed on this work.

This article is a PNAS Direct Submission. U.B. is a guest editor invited by the Editorial Board.

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This article contains supporting information online at www.pnas.org/cgi/content/full/0710081105/DCSupplemental.

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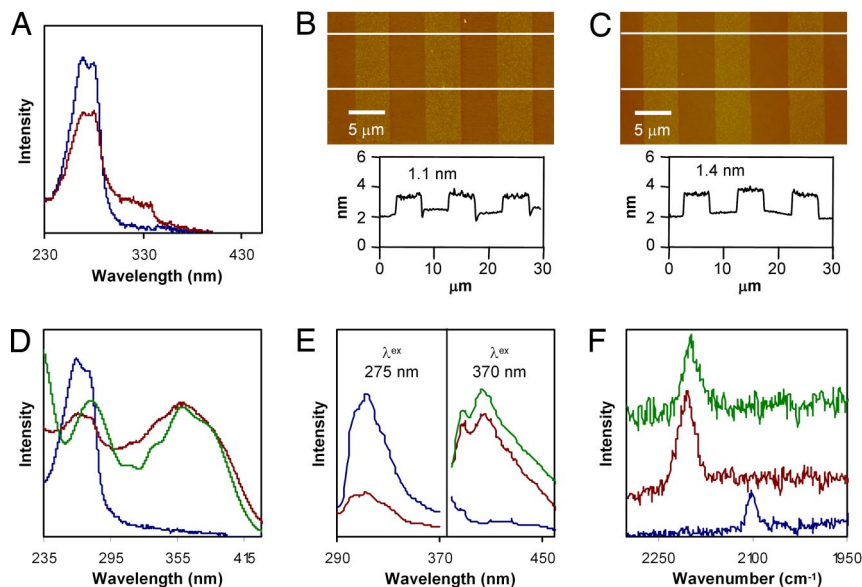


Fig. 2. Spectroscopic data and AFMs of SAMs, linked monolayers, and transferred monolayer membranes. (A) Absorption spectra of a SAM (blue), a linked monolayer (red), from **1** on quartz. (B and C) Tapping-mode AFM of a SAM and a linked monolayer, respectively, from **1** patterned into stripes by photolithography and oxygen-reactive ion etching. The averaged line cuts show a step height of 1.1 nm for the SAM and 1.4 nm for the linked monolayer. (D) Absorption spectra of a SAM (blue), a linked monolayer (red), and a transferred monolayer membrane (green) from **2** on quartz. (E) Fluorescence spectra ($\lambda^{\text{ex}} = 275$ nm, *Left*; $\lambda^{\text{ex}} = 370$ nm, *Right*) of a SAM (blue curves), a linked monolayer (red curves), and an etched monolayer membrane from **2** (green curve) on 330-nm-diameter SiO_2 spheres. Peak heights were normalized to the 315-nm emission of the SAM from **2**. (F) Raman spectra of a SAM (blue), linked monolayer (red), and transferred monolayer membranes on a Si wafer with 300 nm thermal SiO_2 (green) from **2**.

monolayer membrane from **2** transferred to a UV grade quartz slide reveals a small shift of the absorbance peak at 275 nm, but the absorption of poly(1,4-phenylene-1,3-butadiynylene) chromophores at 365 nm remains unchanged (Fig. 2D, green curve). When the monolayer membrane from **2** grown on silicon oxide beads were etched with aqueous HF, the fluorescence spectra (Fig. 2E, green curve) showed a slight increase in intensity, but no change in the overall peak signature ($\lambda^{\text{ex}} = 370$ nm). Finally, when a sample of monolayer membrane from **2** was transferred to a Si wafer with 300 nm thermal SiO_2 , no change in the Raman peak at $2,204\text{ cm}^{-1}$, corresponding to the $\text{C}\equiv\text{C}$ stretching mode in diphenyl diacetylene, was observed (Fig. 2F, green curve). Together, these results suggest that the chemical nature of the monolayer membrane remains unchanged after HF etching and transfer.

We explored the modulus and structural integrity in two different types of experiments. First, the transfer of narrow ribbons of monolayer membranes to prestrained elastomeric substrates of poly(dimethylsiloxane) (PDMS) was studied. Releasing the prestrain leads to a nonlinear buckling instability that produces a one-dimensional, sinusoidal pattern of relief. Fig. 3A shows AFM images of a ribbon of a monolayer membrane from **2** before and after releasing the prestrain. This type of buckling response will only occur in ribbons of material with high levels of structural integrity and moduli that are much higher than the PDMS (29). Quantitative analysis of the buckling wavelength, with the known modulus of the PDMS (30) and the measured thickness of the monolayer membrane, yielded moduli between 1 and 10 GPa. These values are typical of polymers of similar materials. They are lower than single crystals of dicarbazolyl polydiacetylene (45 GPa) (31) and of graphene (≈ 1 TPa) (32). Second, to examine the structural integrity and barrier properties of SAMs, linked monolayers, and transferred monolayer membranes, we used wet etching based chemical amplification (33) to evaluate the area density of defects in the films. The defect densities in linked monolayers on their growth substrates [Si (100) with a native oxide layer] are 1.6×10^3 , 1.4×10^3 , and

9.1×10^2 defects per mm^2 for **1**, **2**, and **3**, respectively (Fig. 3B *Inset*). Several factors could contribute to the density of defects in the linked monolayers, such as defects on growth surfaces, defects in SAMs formation, and defects as a result of polymer shrinkage. Although polymer shrinkage may be an issue, especially for molecule **3**, it is challenging to assess its influence without information on packing density during the SAM formation. In particular, if the initial SAMs are packed very tightly, cross-linkage may actually result in expansion instead of shrinkage. The densities in linked monolayers are ≈ 10 times lower than those of the corresponding SAMs, suggesting a linking mechanism that tends to eliminate defects. The defect densities in the linked monolayers are, in fact, only slightly higher than well developed alkanethiolate SAMs on gold (33), which are known to have much better order and quality than SAMs of silanes. Similar studies performed on a monolayer membrane from **2** transferred to a substrate of Au(200 nm)/Cr(5 nm)/ SiO_2 (300 nm)/Si indicated a ≈ 10 -fold increase in defect density compared with the same linked monolayer on its growth substrate (Fig. 3A). This increase is due, at least in part, to slight mechanical damage during transfer. Release of stresses associated with polymerization shrinkage could also contribute.

Although monolayer films are invisible on most substrates, we found that these transferred monolayer membranes could be visualized directly under an optical microscope when supported by oxidized Si substrates with an oxide layer of 300 nm, similar to observations in single-layer graphene (8). The Si wafer with 300 nm thermal SiO_2 was selected because the phase contrast between the monolayer membrane and the wafer results in a shift from violet-blue to blue (34). For all transferred films, we observed flat, continuous films largely free of defects over areas of several square millimeters (Fig. 3C). Near their edges, these monolayer membranes exhibited folds, holes, and tears, which we attribute to the transfer process.

The transferred monolayer membranes were also analyzed by AFM and transmission electron microscopy (TEM). A folded region of a transferred film from **1** showed clear correlations

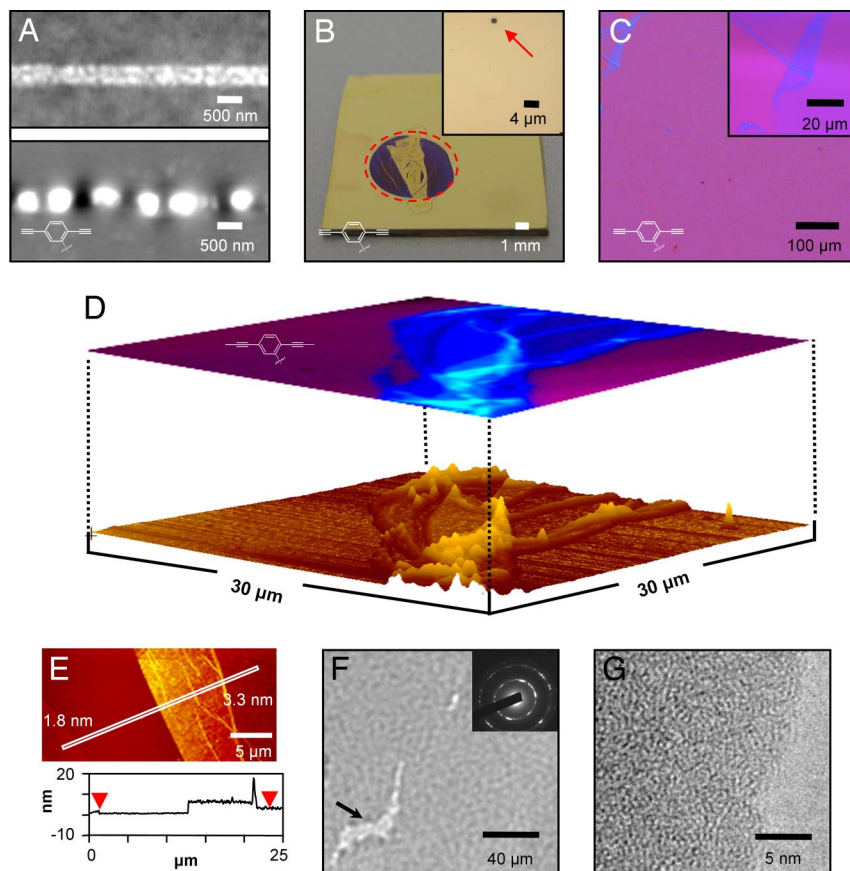


Fig. 3. Characterization of transferred monolayer membranes. (A) AFM images of a ribbon of a monolayer membrane from **2** (width = 500 nm) on a prestrained PDMS substrate before (Upper) and after (Lower) releasing the prestrain. (B) Image of a sample of monolayer membrane from **2** transferred to a substrate of Au(200 nm)/Cr(5 nm)/SiO₂(300 nm)/Si after wet etching the Au with a ferricyanide solution in a circular region (dashed line) surrounding the membrane. The etched areas appear as dark blue; the unetched gold region in the center corresponds to the transferred monolayer membranes. (Inset) An optical micrograph of a silicon substrate that supports a linked monolayer, collected after exposure to KOH etchant. The arrow indicates an etched pit corresponding to a pinhole defect in the monolayer. (C) Reflection mode optical micrograph of a monolayer membrane from **2** transferred to a Si wafer with a 300-nm thermal SiO₂ layer. (Inset) High-magnification micrograph of folds in the film. (D) Reflectance optical micrograph superimposed on tapping-mode AFM image of a monolayer membrane from **1** transferred to a Si wafer with a 300-nm thermal SiO₂ layer. (E) Tapping-mode AFM image and line-cut height profile showing a monolayer membrane from **1** with regions of 1.8- and 3.3-nm height, consistent with folding on transfer to a Si wafer with a 300-nm thermal SiO₂ layer. (F) Low-magnification TEM image of a monolayer membrane from **1** transferred to a holey carbon-coated grid. The arrow points toward a small defect in the film created by the transfer process. (Inset) An electron diffraction pattern with rings at 1.1 Å and 2 Å, but otherwise no significant in-plane ordering. (G) High-magnification TEM image of a monolayer membrane from **1** transferred to holey carbon-coated grid showing a film largely free of pinhole defects.

between thickness determined by tapping-mode AFM and intensity of the optical micrograph (Fig. 3D). The transferred monolayer membrane from **1** has a slightly increased thickness (1.8 nm) that likely results from a layer of water between the film and SiO₂ surface (8). Additionally, a folded area has a thickness (3.3 nm) that is approximately twice the nominal thickness for the rest of the film (Fig. 3E). The folding ability of these nanometer-thick films is a testament of their mechanical strength. TEM images of a monolayer membrane from **1** transferred to a holey carbon grid revealed a tightly packed monolayer with uniform thickness and very few pinhole defects that may have been invisible using AFM (Fig. 3F and G).

The low density of defects and the high structural integrity of the linked monolayers allowed the creation of more exotic film geometries. Transfer of a monolayer membrane from **1** onto a substrate with an array of cylindrical holes (≈ 440 nm diameter, ≈ 400 nm depth) produces suspended monolayer “drumheads” that were nondestructively imaged by AFM and scanning electronic microscopy (SEM; Fig. 4A and B). Again, the absence of torn regions illustrates the remarkable mechanical robustness of these systems.

The ability to form linked monolayers on a wide range of planar, nonplanar, or three-dimensional substrates creates further opportunities for fabrication of unusual structures. For example, a linked monolayer from **1** was formed directly on a substrate with an array of shallow voids (≈ 35 nm), to produce a continuous linked monolayer in the form of a 2D “pleated sheet” (Fig. 4C and D). On transfer of the membrane, the AFM power spectrum shows an in-plane periodicity of the “pleats” that matches that of the growth substrate. However, the relief is only ≈ 1.2 nm, as might be expected from partial or complete folding of the monolayer membrane in the regions corresponding to the edges of relief in the substrate.

This strategy also allowed the formation of linked monolayers on 3D objects as well. SAMs of **1** were deposited on 226 ± 16 nm nonporous SiO₂ spheres with a procedure similar to that used for flat substrates. After linking, the SiO₂ substrate was removed by HF vapor etching to yield empty monolayer membrane “balloons.” Fig. 4 shows TEM images of monolayer-coated spheres (Fig. 4E) and balloons (Fig. 4F). Histograms created from observation of many such objects show a close correspondence between sphere and balloon diameters, but the balloons

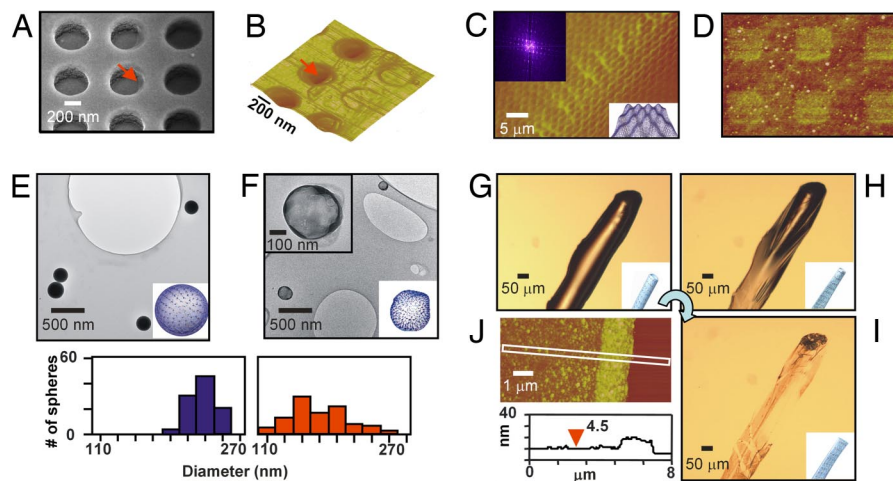


Fig. 4. Images of "unusual" monolayer membrane structures. (A and B) SEM and AFM images, respectively, of a membrane from **1** transferred onto a substrate with a square array of cylindrical holes (diameters ≈ 440 nm and depths ≈ 400 nm) to form "drumhead" structures. Red arrows point to the same region of the film that is suspended over the edge of a hole. (C and D) AFM and high-resolution AFM images, respectively, of a monolayer membrane from **1** grown on a substrate similar to that in A, but with relief depths of ≈ 35 nm, and then transferred to a flat Si wafer with a 300-nm thermal SiO₂ layer. (C Inset Upper Left) Power spectrum of the AFM image, indicating a well defined periodicity consistent with that of the growth substrate. (C Inset Lower Right) Illustration of a "pleated sheet." (E and F) TEM images and diameter distributions of a monolayer membrane from **1** deposited on SiO₂ spheres imaged on a holey carbon-coated grid before (E) and after (F) HF vapor etching of the SiO₂. Insets are illustrations of the imaged structures. (G–I) Time-resolved reflection mode optical micrographs of a tubular membrane from **3** filled with HF/water immediately after HF vapor etching of optical fiber, after 20 min open to the air, and after complete drying, respectively. Insets are illustrations of the imaged structures. (J) AFM image of this collapsed tube. The line scan corresponds to an average over the area indicated by the rectangle.

have a slightly wider distribution and smaller size (diameters, 168 ± 32 nm) because of partial collapse on removal of the silica support. A similar process was carried out with ≈ 125 - μm -diameter optical fibers by using SAMs of **3**. Immediately after the HF vapor etch, water droplets were observed within the hollow fibers. Fig. 4 G, H, and I show time-sequential optical micrographs illustrating evaporation of this encapsulated water. The AFM image in Fig. 4 J shows that the monolayer membrane that remains after drying is consistent with the nominal layer thickness (≈ 4.5 nm center thickness), although capillary forces induced by the contracting HF/water droplet may be responsible for large nonuniformities near the edges. In a saturated environment, the water-filled monolayer membrane tubes maintain their shape for hours without tearing, providing additional evidence of their robustness.

A remaining topic of interest involves how the monolayer membranes are being held together. Although it could be envisioned that these membranes are being held together by polysiloxane formation during SAM deposition, transfer of *unlinked* SAMs of **1** and **2** yielded neither films nor film fragments. For the SAM of **3**, film fragments were observed but they were smaller and contained many more defects than the corresponding monolayer membrane. The small fragments in this case likely result from inadvertent cross-linking by air oxidation or by thermal polymerization under the SAM deposition conditions. Additionally, if these membranes were being held together through polysiloxanes it is highly unlikely that they would stand up to treatment with HF. Exposure of SAMs from **1** and **2** to the linkage conditions, yields linear oligomeric/polymer chains. Conceivably, these chains can be held together in a woven network, although this type of geometry is not necessary to explain the structural integrity of the films; previous studies of related systems indicate that purely noncovalent interactions can yield similar properties (13, 35). However, monolayer membranes from **3** are most likely held together because of multiple cross-linking. Both of these proposed mechanisms would explain the mechanical strength of the monolayer

membranes on removal of the support and their flexibility to adopt the geometry of the given support.

Discussion

In conclusion, we have shown that linked carbon monolayers can be formed on a variety of solid surfaces. These linked monolayers are synthesized by linking three different alkyne-containing monomers with two different carbon–carbon bond-forming reactions [Mo(IV)-catalyzed alkyne metathesis and Cu-catalyzed Hay coupling]. The linked monolayers synthesized on flat surfaces have extremely large aspect ratios and are easily transferred from the native surface by protecting with photoresist and etching the inorganic substrate. These monolayer membranes are sufficiently robust to be suspended over 440-nm-diameter holes without tearing. The linked monolayers were also prepared on structured surfaces and 3D supports, and the freestanding monolayer membranes maintained the shape of the original support after etching. This approach to the synthesis of monolayer carbon networks provides a powerful method to explore the properties and device applications of a wide variety of carbon films. Other linking chemistries and monomers are currently being explored for the synthesis of conducting, 2D monolayer films.

Materials and Methods

Representative Synthesis of SAMs on Flat Substrates. A freshly cleaned and dried substrate was placed in a reaction vial containing a 0.015 M solution of **1** in toluene and TEA (10 mM) under a nitrogen atmosphere. The vial was sealed and heated to 95–100°C for 24 h. The substrate was removed and rinsed once with toluene, twice with dichloromethane, and sonicated for 5 min in toluene. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated and the substrate blown dry under a stream of nitrogen.

Synthesis of Linked Monolayers by Alkyne Metathesis. In a glovebox, 5.0 mg of trisamidomolybdenum(IV) propylidene and 3.3 mg of *p*-nitrophenol were dissolved in 3 ml of trichlorobenzene in a reaction vial. The substrate was added, and the flask was sealed and placed under a vacuum (5 torr) for 22 h. The substrate was removed from the vial and rinsed once with dimethylfor-

mamide (DMF), once with a 0.1 M solution of sodium diethylcarbomdithioate in DMF, once with toluene, twice with dichloromethane, then sonicated in toluene for 5 min. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated a third time and the substrate was blown dry with a stream of nitrogen.

Synthesis of Linked Monolayers by Copper Coupling. In a reaction vial, 20 mg of CuCl was dissolved in 3 ml of degassed acetone. To this suspension was added 61 μ l of TMEDA and the solution was allowed to stir under a nitrogen atmosphere at room temperature for 30 min. At this time, the substrates were added and the reaction vial purged with oxygen from a balloon. The mixture was stirred under an oxygen atmosphere for 15 h. The substrate was removed from the vial and rinsed once with DMF, once with a 0.1 M solution of sodium

diethylcarbomdithioate in DMF, once with toluene, twice with dichloromethane, then sonicated in toluene for 5 min. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated a third time and the substrate was blown dry with a stream of nitrogen.

ACKNOWLEDGMENTS. We thank Prof. J. Notestein, Dr. T. Spila, Dr. R. Haasch, V. Petrova, Tu Truong, Prof. M. Shim, T. Banks, and K. Colravy for helpful discussions and help with analytical facilities. This work was supported by U.S. Department of Energy, Division of Materials Sciences Award DE-FG02-07ER46471, through the Frederick Seitz Materials Research Laboratory. All imaging and surface analysis, supported by Award DE-FG02-91ER45439, was performed at the Frederick Seitz Materials Research Laboratory Center for Microanalysis. S.U. was supported, in part, by the Anandamahidol Foundation.

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Supporting Information

Schultz et al. 10.1073/pnas.0710081105

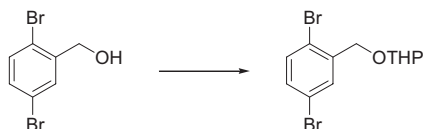
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General. All reagents were purchased and used as received without further purification unless otherwise noted. THF was dried by distilling from a sodium benzophenone ketyl. Triethylamine was dried by distilling from CaH₂. Toluene, methanol, and dichloromethane were dried by passing through a column of activated alumina before use. Ethanol was dried by distilling from magnesium ethoxide. Silicon nitride was deposited by plasma-enhanced chemical vapor deposition (PECVD) onto a silicon wafer with a 300-nm thermal oxide (Process Specialties Inc.). TEM was performed on a JEOL 2010 LaB6 TEM. SEM was performed on a Hitachi S-4700 high-resolution SEM. AFM was performed on a Digital Instruments Dimension 3100 AFM.

Synthesis of Monomers:

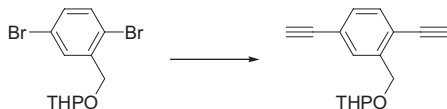
2-(2,5-dibromobenzoyloxy)-tetrahydro-2H-pyran.



In a 250-ml flame-dried, round-bottom flask equipped with a stir bar was placed 2.13 g of 2,5-dibromobenzyl alcohol (8.00 mmol, 1.00 eq) and 0.041 g of TsOH-H₂O (0.24 mmol, 0.03 eq) in 40 ml of dichloromethane. To the suspension was added 2.0 ml of dihydropyran (24.0 mmol, 3.0 eq) by syringe. The reaction mixture was allowed to stir under a N₂ atmosphere at room temperature for 12 h. The reaction mixture was transferred to a separatory funnel, diluted with 50 ml of dichloromethane and washed twice with 20 ml of water and once with 20 ml of brine. The organic layer was dried over MgSO₄, filtered, and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 10% dichloromethane/hexanes to 20% dichloromethane/hexanes to yield 2.26 g of a clear oil (90% yield).

2-(2,5-dibromobenzoyloxy)-tetrahydro-2H-pyran. TLC (EtOAc:Hexanes, 1:4 vol/vol): *R_f* = 0.55; ¹H NMR (500 MHz, CDCl₃): δ 1.53–1.69 (m, 3H), 1.70–1.84 (m, 2H), 1.85–1.96 (m, 1H), 3.55–3.61 (m, 1H), 3.87–3.93 (m, 1H), 4.51 (d, *J* = 13.7 Hz, 1H), 4.77 (d, *J* = 13.7 Hz, 1H), 4.78 (d, *J* = 3.3 Hz, 1H), 7.27 (dd, *J* = 8.5 Hz, *J* = 2.5 Hz, 1H), 7.39 (d, *J* = 8.5 Hz, 1H), 7.66 (d, 2.5, 1H); ¹³C NMR (75 MHz CDCl₃): δ 19.2, 25.3, 30.4, 62.1, 67.8, 98.4, 120.7, 121.4, 131.4, 131.5, 133.6, 140.0; IR: 3054, 2987, 2948, 1266, 734; E.I.-HRMS (*m/z*): [M]⁺ calculated for C₁₂H₁₄Br₂O₂, 347.9361; found, 347.9363.

2-(2,5-Diethynylbenzyloxy)-tetrahydro-2H-pyran.



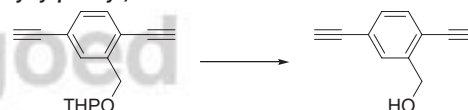
In a 50-ml sealed flask equipped with a stir bar under an argon atmosphere was dissolved 0.71 g of 2-(2,5-dibromobenzoyloxy)-tetrahydro-2H-pyran (2.00 mmol, 1.00 eq), 0.60 g of trimethylsilyl acetylene (6.00 mmol, 3.00 eq), 0.057 g Pd(PPh₃)₂Cl₂ (0.081 mmol, 0.040 eq), 0.080 g PPh₃ (0.031 mmol, 0.15 eq), and 0.039 g CuI (0.20 mmol, 0.10 eq) in 12 ml of triethylamine and 8 ml of THF. The flask was sealed and heated to 80°C for 12 h. The mixture was allowed to cool to room temperature, filtered, and the solvent was removed *in vacuo*. The crude material was filtered through a plug of silica eluting with 1:1 DCM/Hexanes

and the crude product was taken on to the next step without further purification.

The bis(TMS acetylene) was dissolved in 12 ml of a 1:1 mixture of MeOH and DCM in a 50-ml round-bottom flask equipped with a stir bar. To the mixture was added 0.66 g of K₂CO₃ (4.80 mmol, 2.40 eq). After stirring for 12 h under a nitrogen atmosphere at ambient temperature, the mixture was transferred to a separatory funnel and diluted with 30 ml of a saturated solution of NH₄Cl. The aqueous layer was extracted three times with 10 ml of ethyl acetate. The organic extracts were combined and washed once with 10 ml of brine. The organic layer was dried over MgSO₄, filtered, and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 10% DCM/hexanes to 40% DCM/hexanes to yield 0.42 g of a light orange oil (87% yield over two steps).

2-(2,5-diethynylbenzyloxy)-tetrahydro-2H-pyran (DCM:Hexanes, 3:7 vol/vol): *R_f* = 0.25; ¹H NMR (400 MHz, CDCl₃): δ 1.51–1.67 (bm, 3H), 1.68–1.83 (bm, 2H), 1.84–1.96 (bm, 1H), 3.17 (s, 1H), 3.38 (s, 1H), 3.53–3.61 (m, 1H), 3.88–3.96 (m, 1H), 4.66 (d, *J* = 13.8 Hz, 1H), 4.78 (t, *J* = 3.4 Hz, 1H), 4.90 (d, *J* = 13.8 Hz, 1H), 7.66 (dd, *J* = 8.0 Hz, *J* = 1.5 Hz, 1H), 7.43 (d, *J* = 8.0 Hz, 1H), 7.65 (d, *J* = 1.5 Hz, 1H); ¹³C NMR (75 MHz, CDCl₃): δ 19.5, 25.7, 30.7, 62.3, 66.9, 79.1, 80.9, 83.5, 83.8, 98.7, 121.0, 122.9, 130.9, 131.0, 132.7, 141.5; IR: 3289, 2944, 2871, 1201, 1129, 1034; E.I.-HRMS (*m/z*): [M]⁺ calculated for C₁₆H₁₆O₂, 240.1150; found, 240.1154.

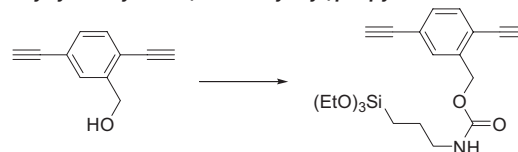
(2,5-Diethynylphenyl)methanol.



To a solution of 0.10 g of 2-(2,5-diethynylbenzyloxy)-tetrahydro-2H-pyran dissolved in 2.5 ml of MeOH in a 10-ml round-bottom flask was added 0.016 g of TsOH-H₂O (0.084 mmol, 0.20 eq). The flask was sealed under a nitrogen atmosphere and allowed to stir for 12 h at ambient temperature. The reaction mixture was transferred to a separatory funnel and diluted with 15 ml of H₂O and extracted three times with 5 ml of DCM. The organic extracts were combined, washed one time with 10 ml of brine, dried over MgSO₄, filtered, and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 50% DCM/Hexanes to DCM to yield 46 mg of a tan solid (71% yield).

(2,5-diethynylphenyl)methanol. mp: 70.5–71.5°C; TLC (DCM:Hexanes, 2:3 vol/vol): *R_f* = 0.18; ¹H NMR (500 MHz CDCl₃): δ 1.16 (t, *J* = 6.1 Hz, 1H), 3.17 (s, 1H), 3.42 (s, 1H), 4.81 (d, *J* = 6.1 Hz, 2H), 7.37 (dd, *J* = 8.0 Hz, *J* = 1.5 Hz, 1H), 7.44 (d, *J* = 8.0 Hz, 1H), 7.59 (dd, *J* = 1.5 Hz, 1H); ¹³C NMR (75 MHz, CDCl₃): δ 63.3, 79.1, 80.6, 83.0, 83.7, 120.5, 122.9, 130.7, 130.9, 132.7, 143.3; IR: 3275, 2925, 2867, 1048, 1026, 890, 828, 690, 623; E.I.-HRMS (*m/z*): [M]⁺ calculated for C₁₁H₈O, 156.0575; found, 156.0573.

2,5-Diethynylbenzyl 3-(triethoxysilyl)propylcarbamate (2).

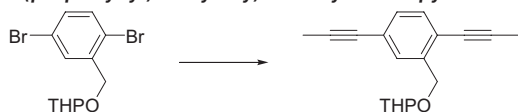


In an oven-dried, 10-ml Schlenk flask equipped with a stir bar, was dissolved 0.080 g of (2,5-diethynylphenyl)methanol (0.51 mmol, 1.0 eq) in 3 ml of THF under a N₂ atmosphere. To this solution was added 0.16 ml of triethoxy(3-isocyanatopropyl)si-

lane (0.67 mmol, 1.3 eq) and 3.0 μ l of dibutyltin dilaurate (0.005 mmol, 0.01 eq) by syringe. The flask was sealed and heated to 60°C. After 18 h, the reaction mixture was cooled to ambient temperature and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 7–20% EtOAc/hexanes to yield 0.17 g of a light-orange liquid (81% yield).

2,5-diethynylbenzyl 3-(triethoxysilyl)propylcarbamate. TLC (EtOAc:Hexanes, 1:4 vol/vol): R_f = 0.19; $^1\text{H NMR}$ (500 MHz CDCl_3): δ 0.59–0.66 (m, 2H), 1.2 (t, J = 7.0 Hz, 9H), 1.57–1.68 (m, 2H), 3.16 (s, 1H), 3.17–3.24 (m, 2H), 3.41 (s, 1H), 3.81 (q, J = 7.0 Hz, 6H), 5.12 (bs, 1H), 5.23 (s, 2H), 7.36 (dd, J = 8.0 Hz, J = 1.3 Hz, 1H), 7.43 (d, J = 8.0 Hz, 1H), 7.52 (d, J = 1.3 Hz, 1H); $^{13}\text{C NMR}$ (75 MHz CDCl_3): δ 7.6, 18.2, 23.2, 43.5, 58.4, 63.9, 79.1, 80.2, 82.9, 83.9, 121.3, 122.7, 131.2, 132.6, 156.1; IR: 3295, 2975, 2927, 2886, 1717, 1700, 1540, 1246, 1077, 957; E.I.-HRMS (m/z): $[\text{M}]^+$ calculated for $\text{C}_{21}\text{H}_{29}\text{NO}_5\text{Si}$, 403.1815; found, 403.1813.

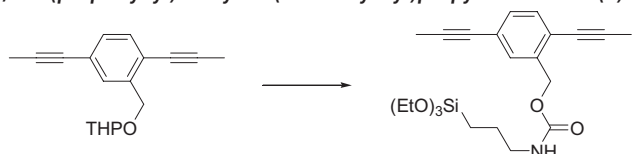
2-(2,5-Di(prop-1-ynyl)benzyloxy)-tetrahydro-2H-pyran.



In a glove box, 0.11 g of prop-1-ynyllithium (2.40 mmol, 3.00 eq) and 0.50 g of zinc bromide (2.20 mmol, 2.80 eq) were dissolved in 3 ml of THF. This solution was then added to a solution of 0.28 g of 2-(2,5-dibromobenzyloxy)-tetrahydro-2H-pyran dissolved in 1.5 ml of THF in a Schlenk tube. To the mixture was added 0.091 g of $\text{Pd}(\text{PPh}_3)_4$ (0.079 mmol, 0.10 eq). The flask was sealed and heated to 60°C for 12 h. The reaction was allowed to cool to ambient temperature, transferred to a separatory funnel, and 25 ml of a saturated solution of NH_4Cl was added. The aqueous layer was extracted three times with 10 ml of diethyl ether. The combined organic layers were washed with 10 ml of brine, dried over MgSO_4 , filtered, and the solvent was removed *in vacuo*. The crude product was purified by column chromatography, eluting with 5% diethyl ether/hexanes to yield 0.18 g of a white solid (86% yield).

2-(2,5-Di(prop-1-ynyl)benzyloxy)-tetrahydro-2H-pyran. mp: 56–58°C; TLC (EtOAc:Hexanes, 1:4 vol/vol): R_f = 0.4; $^1\text{H NMR}$ (500 MHz, CDCl_3): δ 1.49–1.68 (m, 3H), 1.69–1.82 (m, 2H), 1.86–1.96 (m, 1H), 2.05 (s, 3H), 2.08 (s, 3H), 3.53–3.59 (m, 1H), 3.90–3.97 (m, 1H), 4.60 (d, 13.2, 1H), 4.76–4.79 (m, 1H), 4.85 (d, J = 13.2 Hz, 1H), 7.21 (dd, J = 8.5 Hz, J = 1.8 Hz, 1H), 7.28 (d, J = 8.5 Hz, 1H), 7.50 (d, J = 1.8 Hz, 1H); $^{13}\text{C NMR}$ (75 MHz, CDCl_3): δ 4.4, 4.6, 19.2, 25.4, 30.5, 61.8, 66.9, 77.1, 79.7, 87.1, 91.8, 98.2, 121.4, 123.2, 129.92, 129.93, 131.8, 140.2; IR: 2943, 2868, 1486, 1201, 1130, 1033; C.I.-HRMS (m/z): $[\text{M}+\text{H}]^+$ calculated, 269.1542; found, 269.1548.

2,5-Di(prop-1-ynyl)benzyl 3-(triethoxysilyl)propylcarbamate (1).

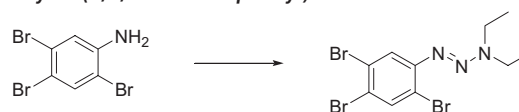


In a 25-ml flame-dried, round-bottom flask was dissolved 0.14 g of 2-(2,5-di(prop-1-ynyl)benzyloxy)-tetrahydro-2H-pyran (0.54 mmol, 1.00 eq) in 2.5 ml of MeOH and 1 ml of dichloromethane. To this solution was added 0.020 mg of $\text{TsOH}\cdot\text{H}_2\text{O}$ (0.11 mmol, 0.20 eq) and the reaction mixture was allowed to stir for 12 h under a N_2 atmosphere at room temperature. The reaction mixture was transferred to a separatory funnel and diluted with 25 ml of a saturated solution of NaHCO_3 . The aqueous layer was extracted three times with 10 ml of dichloromethane. The combined extracts were washed once with 10 ml of brine, dried over MgSO_4 , filtered, and the solvent was removed *in vacuo* to yield a white solid. The solid was dissolved in 3 ml of dry THF

and placed under a N_2 atmosphere. To this solution was added 0.17 ml of triethoxy(3-isocyanatopropyl)silane (0.70 mmol, 1.30 eq) and 3.2 μ l of dibutyltin dilaurate (0.0054 mmol, 0.010 eq) by syringe. A condenser was attached to the flask, and the reaction mixture was heated to reflux under a N_2 atmosphere. After 18 h, the reaction mixture was cooled to ambient temperature and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 10% acetone/hexanes to yield 210 mg of a white solid (86% yield over two steps).

2,5-di(prop-1-ynyl)benzyl 3-(triethoxysilyl)propylcarbamate. mp: 54–56°C; TLC (EtOAc:Hexanes, 3:7 vol/vol) R_f = 0.4; $^1\text{H NMR}$ (500 MHz, CD_2Cl_2): δ 0.57 (m, 2H), 1.20 (t, J = 7.1 Hz, 9H), 1.54–1.66 (m, 2H), 2.04 (s, 3H), 2.08 (s, 3H), 3.13–3.21 (m, 2H), 3.80 (q, J = 7.1 Hz, 6H), 5.06–5.13 (bs, 1H), 5.16 (s, 2H), 7.22 (d, J = 8.0 Hz, 1H), 7.29 (d, J = 8.0 Hz, 1H), 7.37 (s, 1H); $^{13}\text{C NMR}$ (75 MHz, CD_2Cl_2): δ 4.4, 4.6, 7.9, 18.4, 23.7, 43.9, 50.6, 64.5, 76.9, 79.5, 87.8, 92.9, 122.3, 123.7, 130.65, 130.74, 132.2, 139.0, 156.4; IR: 3328, 2974, 2927, 2884, 1696, 1540, 1282, 1259, 1082; C.I.-HRMS (m/z): $[\text{M}]^+$ calculated, 432.2206; found, 432.2205.

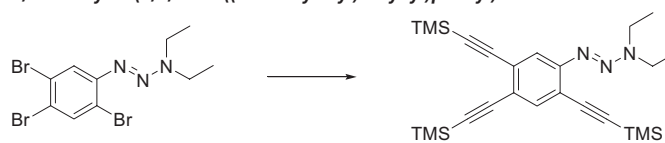
3,3-Diethyl-1-(2,4,5-tribromophenyl)triaz-1-ene.



In a stirred solution of 0.93 g of 2,4,5-tribromoaniline (2.80 mmol, 1.00 eq) dissolved in 6 ml of acetonitrile, 2 ml of THF, and 3 ml of water in a 100-ml round-bottom flask, was added with 2.4 ml of concentrated HCl (28.3 mmol, 10.0 eq) to form a light-orange slurry. The mixture was cooled to -10°C and a solution of 0.41 g of NaNO_2 (5.90 mmol, 2.10 eq) dissolved in 2 ml of water and 1 ml of acetonitrile was added dropwise by syringe over 20 min maintaining a temperature below -5°C . The mixture was stirred for an additional 15 min at -10°C and then transferred by cannulation to a solution of 2.1 g of diethylamine (28.3 mmol, 10.0 eq) and 19.6 g of K_2CO_3 (14.2 mmol, 10.0 eq) dissolved in 6 ml of acetonitrile and 12 ml of water maintaining a temperature $<0^\circ\text{C}$. This mixture was allowed to warm to room temperature and stirred for 4 h. The mixture was transferred to a separatory funnel, diluted with 100 ml of diethyl ether and washed twice with 100 ml of brine. The organic layer was dried over MgSO_4 , filtered, and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 3% DCM/hexanes to yield 0.70 g of an orange solid (60% yield).

3,3-Diethyl-1-(2,4,5-tribromophenyl)triaz-1-ene. mp: 46–50°C; TLC (DCM:Hexanes, 1:4 vol/vol): R_f = 0.42; $^1\text{H NMR}$ (500 MHz, CDCl_3): δ 1.2–1.5 (bd, 6H), 3.80 (bs, 4H), 7.66 (s, 1H), 7.80 (s, 1H); $^{13}\text{C NMR}$ (75 MHz, CDCl_3): δ 10.6, 14.4, 42.3, 49.5, 118.7, 119.8, 122.4, 123.8, 136.4, 148.4; IR: 3079, 2973, 2930, 2867, 1440, 1401, 1328, 1109, 1042, 884; E.I.-HRMS (m/z): $[\text{M}]^+$ calculated for $\text{C}_{10}\text{H}_{12}\text{Br}_3\text{N}_3$, 410.8581; found, 410.8585.

3,3-Diethyl-1-(2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)triaz-1-ene.

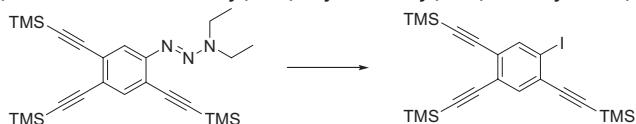


In a 100-ml sealed flask equipped with a stir bar under an argon atmosphere was dissolved 1.7 g of 3,3-diethyl-1-(2,4,5-tribromophenyl)triaz-1-ene (4.0 mmol, 1.0 eq), 1.8 g of trimethylsilyl acetylene (18.0 mmol, 4.5 eq), 0.14 g of $\text{Pd}(\text{PPh}_3)_2\text{Cl}_2$ (0.20 mmol, 0.050 eq), 0.21 g of PPh_3 (0.80 mmol, 0.20 eq), and 76.0 mg of CuI (0.4 mmol, 0.1 eq) in 40 ml of a 1:1 mixture of TEA/THF. The flask was sealed and heated to 70°C for 12 h. The mixture was allowed to cool to room temperature, filtered, and the solvent was removed *in vacuo*. The crude material was

purified by column chromatography eluting with 5% Et₂O/hexanes to yield 1.7 g of a light-yellow solid (94% yield).

(3,3-diethyl-1-(2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)triaz-1-ene. mp: 104–108°C; TLC (EtOAc:Hexanes, 1:4 vol/vol): R_f = 0.68; ¹H NMR (400 MHz, CDCl₃): δ 0.22 (s, 9H), 0.25 (s, 9H), 0.26 (s, 9H), 1.22–1.38 (bm, 6H), 3.72–3.86 (bs, 4H), 7.51 (s, 1H), 7.60 (s, 1H); ¹³C NMR (75 MHz, CDCl₃): δ –0.04, 0, 0.1, 11.0, 14.5, 42.0, 49.4, 97.9, 99.1, 100.1, 102.1, 102.9, 103.4, 118.2, 120.2, 121.5, 125.9, 137.3, 151.8; IR: 2960, 2152, 1379, 1249, 841; E.I.-HRMS (m/z): [M]⁺ calculated for C₂₅H₃₉N₃Si₃, 465.2452; found, 465.2447.

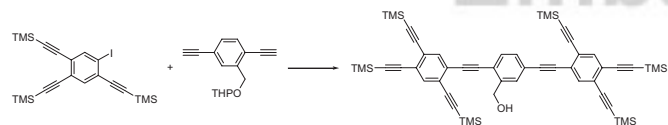
(5-Iodobenzene-1,2,4-triyl)Tris(ethyne-2,1-diyl)Tris(trimethylsilane).



A solution of 0.28 g of (3,3-diethyl-1-(2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)triaz-1-ene (0.59 mmol) dissolved in 5.9 ml of iodomethane was placed in a sealed flask under a nitrogen atmosphere and heated to 125°C for 14 h. The mixture was allowed to cool to room temperature and a small amount of silica was added. The solvent was removed *in vacuo* and the crude material was purified by column chromatography eluting with 2% DCM/hexanes to yield 0.26 g of a yellow solid (88% yield).

(5-Iodobenzene-1,2,4-triyl)Tris(ethyne-2,1-diyl)Tris(trimethylsilane). mp = 85–88°C; TLC (EtOAc:Hexanes, 1:4 vol/vol): R_f = 0.76; ¹H NMR (400 MHz, CDCl₃): δ 0.22 (s, 9H), 0.25 (s, 9H), 0.26 (s, 9H), 7.54 (s, 1H), 7.92 (s, 1H); ¹³C NMR (75 MHz, CDCl₃): δ –0.34, –0.14, 98.9, 100.4, 101.2, 101.3, 101.5, 101.7, 125.5, 126.5, 129.5, 135.6, 141.9; IR: 2957, 2897, 2159, 1462, 1248, 841, 761; E.I.-HRMS (m/z): [M]⁺ calculated for C₂₁H₂₉I₃Si₃, 492.0622; found, 492.0671.

(2,5-Bis((2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)ethynyl)phenyl methanol.

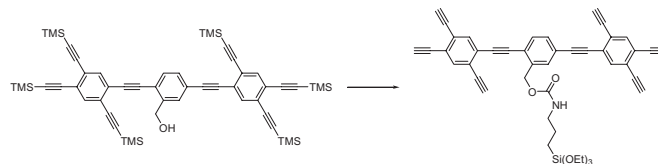


In a 20-ml sealed flask equipped with a stir bar under an argon atmosphere was dissolved 0.11 g of 2-(2,5-diethynylbenzyloxy)-tetrahydro-2H-pyran (0.45 mmol, 1.00 eq), 0.49 g of (5-Iodobenzene-1,2,4-triyl)Tris(ethyne-2,1-diyl)Tris(trimethylsilane) (1.00 mmol, 2.20 eq), 0.016 g of Pd(PPh₃)₂Cl₂ (0.023 mmol, 0.050 eq), 0.012 g of PPh₃ (0.045 mmol, 0.10 eq), and 8.6 mg of CuI (0.05 mmol, 0.1 eq) in 3 ml of triethylamine and 2 ml of THF. The flask was sealed and stirred at room temperature for 8 h, then heated to 45°C for 12 h. The mixture was allowed to cool to room temperature, filtered, and the solvent was removed *in vacuo*. The crude material was purified by column chromatography eluting with 10% EtOAc/hexanes then 7% acetone/hexanes to produce a light-yellow solid that was not purified further.

To the crude solid was added 6 ml of MeOH and ≈2 ml of DCM followed by 17.0 mg of TsOH·H₂O (0.09 mmol, 0.2 eq). The mixture was allowed to stir overnight at room temperature under a N₂ atmosphere. The reaction mixture was transferred to a separatory funnel, diluted with 30 ml of a saturated solution of NaHCO₃, and extracted three times with 15 ml of DCM. The organic extracts were combined and washed one time with 10 ml of brine, dried over MgSO₄, filtered, and the solvent was removed *in vacuo*. The crude product was purified by column chromatography eluting with 4% acetone/hexanes to 15% acetone/hexanes to yield 0.27 g of a light-yellow solid (68% yield over two steps). All chromatography solvents contained ≈0.5% triethylamine.

(2,5-bis((2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)ethynyl)phenyl) methanol. mp: dec. 135°C; TLC (DCM:Hexanes, 1:4 vol/vol): R_f = 0.36; ¹H NMR (500 MHz, CDCl₃): δ 0.26–0.32 (m, 54H), 4.89 (s, 2H), 7.44 (dd, J = 7.9 Hz, J = 1.7 Hz, 1H), 7.52 (d, J = 7.9 Hz, 1H), 7.59–7.66 (m, 5H); ¹³C NMR (75 MHz, CDCl₃): δ –0.1, 0, 63.6, 89.5, 92.7, 94.0, 95.4, 101.5, 101.6, 101.7, 101.75, 101.8, 101.9, 102.1, 102.15, 102.2, 102.25, 102.3, 102.5, 125.1, 125.4, 125.6, 125.7, 125.8, 125.9, 126.0, 130.5, 130.9, 132.8, 135.8, 135.9, 136.4, 136.9, 143.9; IR: 2959, 2899, 2157, 1250, 879, 842, 760; E.I.-MS (m/z): [M]⁺ calculated for C₅₃H₆₄O₃Si₆, 884.3573; found, 884.3577.

2,5-Bis((2,4,5-triethynylphenyl)ethynyl)benzyl 3-(triethoxysilyl)propylcarbamate (3).



To a solution of 0.24 g of (2,5-bis((2,4,5-Tris(trimethylsilyl)ethynyl)phenyl)ethynyl) phenyl) methanol (0.27 mmol, 1.00 eq) dissolved in 3 ml of MeOH and 3 ml of THF was added 0.33 g of K₂CO₃ (2.44 mmol, 9.00 eq). After stirring for 8 h at room temperature, the slurry was transferred to a separatory funnel, diluted with 25 ml of brine, and extracted three times with 15 ml of THF. The organic extracts were combined and washed with 10 ml of brine, dried over MgSO₄, filtered through a plug of silica, and the solvent was removed *in vacuo*.

The crude solid was dissolved in 5 ml of THF in a 25-ml Schlenk flask under a nitrogen atmosphere. To the flask was added 0.087 ml of triethoxy(3-isocyanatopropyl)silane (0.35 mmol, 1.30 eq) and 1.6 μl of dibutyltin dilaurate (0.002 mmol, 0.01 eq). The flask was sealed and heated to 55°C for 18 h. The solvent was removed *in vacuo* and the crude material was purified by column chromatography eluting with 40% DCM/hexanes then 40% DCM/10% acetone/hexanes all containing ≈0.5% TEA to yield 116 mg of a light-yellow solid (60% yield over two steps).

2,5-bis((2,4,5-triethynylphenyl)ethynyl)benzyl 3-(triethoxysilyl)propylcarbamate. mp: dec. 125°C; TLC (Acetone:Hexanes, 1:1 vol/vol) R_f = 0.65; ¹H NMR (500 MHz, CDCl₃): δ 0.55–0.71 (m, 2H), 1.21 (t, J = 6.9, 9H) 1.60–1.70 (m, 2H), 3.19–3.27 (m, 2H), 3.42–3.46 (m, 4H), 3.50 (s, 1H), 3.72, (s, 1H), 3.81 (q, J = 6.9 Hz, 6H), 5.12–5.19 (bs, 1H), 5.39, (s, 2H), 7.47 (d, J = 8.1 Hz, 1H), 7.50 (d, J = 8.1 Hz, 1H), 7.63 (s, 1H), 7.65–7.70 (m, 4H); ¹³C NMR (75 MHz, CD₂Cl₂): δ 7.9, 18.5, 23.6, 43.9, 58.7, 64.7, 80.75, 80.80, 80.85, 80.9, 81.0, 83.69, 83.71, 83.75, 83.8, 84.0, 85.1, 89.0, 92.9, 93.7, 95.6, 121.9, 123.7, 125.13, 125.15, 125.2, 125.22, 125.5, 125.6, 126.4, 126.5, 130.9, 131.2, 132.9, 136.1, 136.2, 136.8, 136.9, 140.0, 156.4; IR: 3286, 2973, 2926, 2884, 1685, 1498, 1252, 1078; FAB-HRMS (m/z): [M]⁺ calculated for C₄₅H₃₇NO₅Si, 699.2441; found, 699.2442.

Preparation of Flat Samples. Silicon oxide, silicon nitride, and quartz (75 mm × 25 mm × 1 mm purchased from Chemglass) substrates were cleaned before use by heating to 90°C in a 3:1 H₂SO₄/H₂O₂ solution for 2 h (caution: piranha solution is explosive and care should be taken while using this mixture). The substrates were rinsed thoroughly with deionized water, then blown dry with a stream of nitrogen.

Representative Synthesis of SAMs on Flat Substrates. A freshly cleaned and dried substrate was placed in a reaction vial containing a 0.015 M solution of 2,5-di(prop-1-ynyl)benzyl 3-(triethoxysilyl)propylcarbamate in toluene and TEA (10 mM) under a nitrogen atmosphere. The vial was sealed and heated to

95–100°C for 24 h. The substrate was removed and rinsed once with toluene, twice with dichloromethane, and sonicated for 5 min in toluene. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated and the substrate blown dry under a stream of nitrogen.

Preparation of SiO₂ and Spheres and Glass Fibers. Nonporous 330-nm SiO₂ spheres purchased from Bangs Laboratories and 125- μ m optical fibers (stripped of acrylate coating) purchased from Thorlabs were cleaned by heating to 90°C for 2 h in a 6 M solution of HCl. The objects were rinsed with water, methanol, and dichloromethane followed by drying under vacuum at 100°C overnight.

Representative Synthesis of SAMs on Objects. Freshly cleaned and dried objects were placed in a reaction vial containing a 0.015 M solution of 2,5-di(prop-1-ynyl)benzyl 3-(triethoxysilyl)propylcarbamate in ethanol and TEA (10 mM) under a nitrogen atmosphere. The vial was sealed, heated to 95–100°C, and stirred by a rotatory plate for 24 h. The substrates were removed and rinsed twice with methanol, twice with dichloromethane, and sonicated for 5 min in methanol.

Synthesis of C³M_s on Flat Surfaces by Mo(IV) Alkyne Metathesis. In a glovebox, 5.0 mg of trisamidomolybdenum(IV) propylidyne (*I*) and 3.3 mg of *p*-nitrophenol were dissolved in 3 ml of trichlorobenzene in a reaction vial. The substrate was added, the flask was sealed, and then placed under a vacuum of \approx 20 in of Hg for 22 h. The substrate was removed from the vial and rinsed once with DMF, once with a 0.1 M solution of sodium diethylcarbamodithioate in DMF, once with toluene, twice with dichloromethane, then sonicated in toluene for 5 min. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated a third time and the substrate was blown dry with a stream of nitrogen.

Synthesis of C³M_s on Objects by Mo(IV) Alkyne Metathesis. The same procedure used for flat surfaces was followed, except objects were cleaned by transferring to microcentrifuge tubes exposed to repeated washing/centrifuge cycles with same solvents as above.

Synthesis of C³M_s by Cu-coupling. In a reaction vial was dissolved 20 mg of CuCl in 3 ml of dry, degassed acetone. To this suspension was added 61 μ l of TMEDA and the solution was allowed to stir under a nitrogen atmosphere at room temperature for 30 min. At this time, the substrates were added and the reaction vial purged with oxygen from a balloon. The mixture was stirred under an oxygen atmosphere for 15 h. The substrate was removed from the vial and rinsed once with DMF, once with a 0.1 M solution of sodium diethylcarbamodithioate in DMF, once with toluene, twice with dichloromethane then sonicated in toluene for 5 min. The rinse was repeated and the substrate was sonicated for 5 min in methanol. The rinse was repeated a third time and the substrate was blown dry with a stream of nitrogen.

Film Transfer. A photoresist (AZ 5214, Clariant) layer was uniformly spin-coated onto a silicon nitride-coated wafer with a monolayer at 3,000 rpm for 30 s and baked at 110°C for 2 min. The wafer was then exposed to a 49% HF solution for 2 min. The sample was then submerged in water to release the photoresist/monolayer film from the wafer. The photoresist/monolayer film was transferred to another solid surface (i.e., Si wafer with 300-nm thermal SiO₂) by carefully dipping a solid substrate into the water and removing with photoresist/monolayer film on top. The photoresist was finally removed by sonicating in acetone for 5 min, rinsing with IPA, DI water, and drying under a stream of nitrogen, to leave only monolayer film on the new solid support.

Line and Space Patterning for Height Measurement. First, the substrate, which has a C³M film grown on Si wafer with 300-nm SiO₂, was spin-coated with a photoresist (AZ 5214, Clariant) at 3,000 rpm for 30 s, followed by prebaking at 110°C for 2 min. Second, the substrate was aligned with a 5- μ m line/space chrome mask on the MJB3 mask aligner (SUSS MicroTec) and exposed to a UV Hg lamp (365 nm) for 9 s with an intensity of 12 mW/cm². The substrate was then developed in a developer (AZ 327 MIF developer, Clariant) for 40 s resulting in 5- μ m line/space photoresist stripes on the substrate. Next, the substrate was exposed to oxygen plasma (20 sccm O₂, 150 mTorr, 150 W) by a reactive ion-etching system (Unaxis, Plasma Thermx) for 30 s. The photoresist was finally removed by sonicating in acetone for 5 min, rinsing with IPA, DI water, and drying under a stream of nitrogen.

Contact Angle Measurements. The advancing contact angles were measured with a Ramé-Hart 100 goniometer. Contact angles were measured on six different spots of the polished side of the silicon wafer for each sample.

UV-Visible Spectroscopy. The UV-vis absorption spectra were recorded on a Shimadzu (UV-160A) spectrophotometer. The monolayers grown on a quartz slide (Chem Glass, UV-grade, 92% transmission at 270 nm) were placed in a 1-cm cuvette and the absorbance was measured by using a clean quartz slide as a background.

Fluorescence Spectroscopy. Fluorescence spectra were recorded on a Photon Technology International (QM-1) fluorometer by suspending the nonporous silicon oxide sphere with SAMs or C³M_s in methanol (\approx 1 mg/ml) in a 1 cm quartz cuvette.

Secondary ion mass spectrometric measurements were carried out in a TOF-SIMS instrument (Cameca) equipped with a cesium ion gun. We measured SIMS of both SAMs and C³M_s on their growth substrates and observed SIMS fingerprint spectra (supporting information (SI) Fig. S2) with complex correlations to the molecular weight fragments. Moreover, only small fragments (mass-to-charge ratio <400) from polymers were emitted because of chemical degradation by the high fluence of ions.

Raman Spectroscopy. The light scattered by the samples was analyzed with a Spex triplemate triple-grating monochromator (SPEX Industries) with the entrance slit set at 200 μ m, a liquid-N₂-cooled CCD detector (Roper Scientific), and a data acquisition system (Photometrics). A video camera was also attached to the front port of the monochromator to facilitate laser alignment and positioning of the samples. Laser excitation (514.5 nm) was provided by an Ar ion laser (Coherent). All of the measurements were performed in ambient conditions.

Buckling Measurements of Mechanical Modulus and Structural Integrity. The modulus measurements involved several steps. First ribbons were fabricated and transferred to a prestrained slab of PDMS. Specifically, this process started with the sputter deposition of a uniform layer of Au (thickness, \approx 100 nm) on a C³M on its SiO₂/Si growth substrate. This Au layer played the role of structural support during the transfer. Next, a layer of photoresist (diluted AZ5214, 1:1 with AZ thinner, 3,000 rpm, 1min.) was spin cast on this substrate. Conformal contact of a PDMS phase mask consisting of 5 μ m/5 μ m line-and-space patterns, followed by flood exposure to UV light (Karl SUSS, contact aligner) for 7 s patterned the exposure of the resist, by a near-field phase-shift photolithography technique (2, 3). After removing the PDMS phase mask, the substrate was developed for 20 s in developer (AZ 327 MIF), thereby yielding \approx 500-nm-wide lines of photoresist, spaced by \approx 5 μ m. These features of resist acted as an etch mask in an ion-milling process that removed the

SF2

exposed Au/C³M. Oxygen plasma (PlasmaTherm) then removed the remaining photoresist. Dipping the substrate in HF undercut etched the SiO₂ and released ribbons of Au/C³M from the substrate. A flat slab of PDMS (10:1 weight ratio of base to curing agent; Dow-Corning Sylgard 184) was used to pick up the released ribbons (still on substrate). At this stage, the ribbons were inverted, i.e., the C³M was exposed to air while the Au layer was in contact with the PDMS. Another piece of PDMS, cured (20:1 weight ratio of base to curing agent; Dow-Corning Sylgard 184) and prestrained to 20–30%, was gently contacted and slowly peeled off of the PDMS with the ribbons of Au/C³M, thereby transferring these ribbons to the PDMS (20:1) slab. While maintaining the prestrain, the exposed Au was removed with an Au etchant (Transcene, Inc.) and thoroughly rinsed with deionized water. Finally, the prestrain was released to induce buckling in the C³M. The samples, before and after release of the prestrain, were characterized by atomic force microscopy, AFM (Asylum, MFD).

For the calculation of the modulus of the C³M, the following formula (4) was used:

$$E_{C^3M} = \left(\frac{\lambda}{2\pi h} \right)^3 \left[\frac{3(1 - \nu_{C^3M}^2) E_{PDMS}}{1 - \nu_{PDMS}^2} \right],$$

where E_{PDMS} and E_{C^3M} are the moduli of the PDMS and C³M, respectively, ν_{PDMS} and ν_{C^3M} are the Poisson ratios, h is the thickness of the C³M, and λ is the buckling wavelength. Analysis by AFM indicates that λ is 630 ± 60 nm, for this system. The modulus of PDMS is ≈ 0.6 MPa, and its Poisson ratio is ≈ 0.5 (5). The value of ν_{C^3M} was assumed to be 0.3. (The computed modulus depends weakly on this quantity, with only 8% change for values of ν_{C^3M} between 0.3 and 0.5). The moduli extracted from this type of analysis of samples of C³M 2 were between 1 and 10 GPa. These values are typical of polymers of similar materials. They are lower than single crystals of the of dicarbazolyl polydiacetylene (45 GPa) (6) and of graphene (≈ 1 TPa) (7).

Chemical Amplification. The chemical amplification process for evaluating the defect densities and barrier properties of SAMs and C³M on their growth substrates consisted of: (i) formation of SAMs and C³M on Si (100) wafers with native oxide; (ii) anisotropic etching of Si (KOH (52 g)/H₂O (226 ml)/IPA (74 ml), 70°C, 25 min) to convert and amplify defects in the SAMs and C³M into easily imaged, micrometer-scale pits in the Si, and (iii) imaging the pits by optical microscopy. The Fig. 3A *Inset* image was collected after step *iii*. The process for evaluating transferred C³M consisted of: (i) transfer of a C³M onto a substrate of Au(200 nm)/Cr(5 nm)/SiO₂(300 nm)/Si with Au and Cr deposited by electron beam evaporation, and SiO₂ grown thermally; (ii) exposure of the C³M/Au/Cr/SiO₂/Si substrate to an etchant for Au (Transene, Inc.); (iii) immersion in aqueous HF to remove exposed SiO₂ in the regions where the gold was removed; (iv) anisotropic etching of the Si (KOH (52 g)/H₂O (226 ml)/IPA (74 ml), 70°C, 25 min) to convert and amplify defects in the exposed regions into easily imaged, micrometer-scale pits in the Si; (v) removal of the remaining gold by aqua regia; and (vi) imaging the pits in the etched silicon substrate by optical microscopy. The main image in Fig. 3A was collected after step *ii*.

Electrical Measurements. Field effect transistor devices were used to probe the charge transport characteristics of the C³M. Two types of devices were fabricated. The first used a conventional back-gate geometry with a doped Si wafer as the gate and a layer of thermally grown SiO₂ as the gate dielectric. In the first step of the fabrication of this type of device, a thin layer of isopropyl alcohol (IPA) was placed on a C³M grown a SiO₂(300 nm)/Si substrate. A shadow mask, based on a TEM grid (Gilder Grids,

150 Mesh, Ted Pella, Inc.), was then placed on the IPA surface. Evaporation of IPA led to good physical contact of the shadow mask with the C³M because of the action of capillary forces. Blanket electron beam evaporation (10^{-6} Torr; Temescal BJD 1800) of Ti (5 nm) and Au (50 nm) formed square-shaped contact pad arrays to define source and drain electrodes and channels with widths and lengths of 230 μ m and 14 μ m, respectively. Electrical measurements on C³M were carried out in air by using a semiconductor parameter analyzer (Agilent 4155C), using an Agilent Metrics I/CV Lite program and a GBIP communication interface to a computer. Triaxial and coaxial shielding were used with a Signatone probe station to yield high signal-to-noise ratio measurements of small current levels. Measurements on these devices at room temperature reveal the resistivities on the order of 10^5 - 10^6 Ω ·cm, independent of gate bias.

The second type of transistor device used polymer electrolyte gating. In this case, source and drain electrodes were patterned in the same geometries and with the same techniques as those used for the conventional devices described earlier. A solution 30% 1:3 (w:w) LiClO₄:polyethyleneimine in methanol was used as the polymer electrolyte. The electrolyte was placed in a poly-(dimethylsiloxane) fluidic channel formed with a piece of molded PDMS on top of a C³M. A silver wire immersed in the electrolyte was used to apply gate voltages between -0.5 V and 0.5 V. The bias between the source and drain electrodes was 0.1 V. The measured source-drain currents were smaller than ≈ 10 nA, comparable to the gate leakage in these devices. The conclusions from these measurements are consistent with those from devices with the more conventional back-gate device geometry.

Preparation of Substrate with Patterned Holes. A substrate with patterned holes was prepared by using Solvent Assisted Micro-Molding (SAMIM) (8). First, a film of epoxy with the thickness of ≈ 10 μ m (NanoSU-8, MicroChem, formulation 10) was deposited onto a glass slide by spin coating at 3,000 rpm for 30 s, followed by soft-baking at 65°C and 95°C for 1 min and 5 min, respectively. Second, the quasi-3D type of mold made of acryloyl perfluoropolyether (a-PFPE) was wetted with ethanol and gently placed into conformal contact on soft-baked substrate from the first step for 30 min. The mold was then peeled off from the substrate followed by exposure of the substrate to a UV Hg lamp (365 nm) from an MJB3 mask aligner (SUSS MicroTec) for 30 s with an intensity of 12 mW/cm² and rebaked at 65°C and 95°C for 1 min and 5 min, respectively. Finally, the substrate was hard-baked at 180°C for 5 min and coated with thin films of Ti/Au (2 nm/ 50 nm) by an electron beam evaporation system (Temescal).

Preparation of Smoothed Patterned Substrate. The procedure above was followed except the SU-8 was spin-coated on a silicon wafer. The steps were smoothed by exposure to thermal flow at 60°C for 6 min after peeling off the mold and before UV exposure. This smoothing resulted in a decrease of the steps from 350 nm to 35 nm and the sharp edges became sloped (Fig. S5). Finally, a 50-nm silicon oxide film was deposited onto the plasmonic crystal using PECVD instead of coating with Ti/Au films.

High-resolution Microscopic Characterizations of C³M 1. The STM image (Fig. S6A) was obtained by transferring C³M 1 onto a freshly cleaved highly oriented pyrolytic graphite surface. Although certain insights can be obtained from such images, molecular scale detail was difficult to obtain. We believe that residue associated with manipulation and synthesis of the C³M represent the main challenge to achieving molecular resolution (9). As an alternative, we conducted ultra-high-resolution AFM

measurements with AFM tips that have radii of curvature as small as 2 nm. Fig. S6B shows a typical result. The rms roughness of C³M **1** is 0.17 nm, nearly identical to that of the bare SiO₂ growth surface. No filamentary structures were visible. For a final set of data, we performed high-resolution TEM on transferred C³M **1** under low-dose conditions. Images (Fig. S6C) show what appear to be strands of polymers separated by a distance of ≈3.35 Å, which might provide direct information on the possibility of woven-network structures. These features may, however, be caused by even slight damage induced by exposure to the electron beam.

XPS Spectroscopy for Characterization of Metal Content. XPS spectroscopy was used to determine whether metal remains on the surface after the Mo(IV) catalyzed linkage of a SAM of **1**. We found the doublet for Mo(3d_{5/2}) and Mo(3d_{3/2}) at 226 and 239 eV, corresponding well to the literature data for Mo (10). A strong C(1s) peak appeared at 283 eV. Integration of the XPS peaks for Mo and C generated a molybdenum-to-carbon ratio of 1.45% at the surface. Quantitative analysis of trace amount of Cu catalysts in linked SAMs from **2** and **3** was difficult because of the low kinetic energy the photoelectrons.

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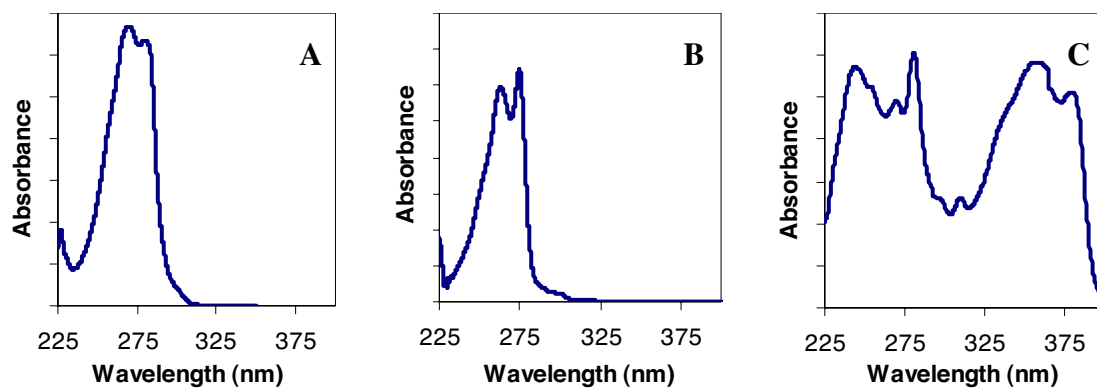


Fig. S1. UV-vis spectra of monomers in dichloromethane. (A) Dipropyne monomer 1. (B) Diacetylene monomer 2. (C) Terphenyl monomer 3.

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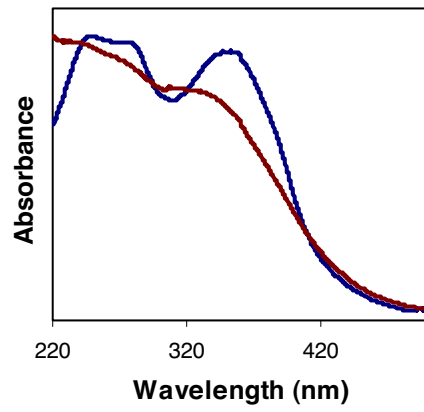


Fig. S2. UV-vis spectra of a SAM of 3 (blue) and linked SAM from 3 (red) on quartz.

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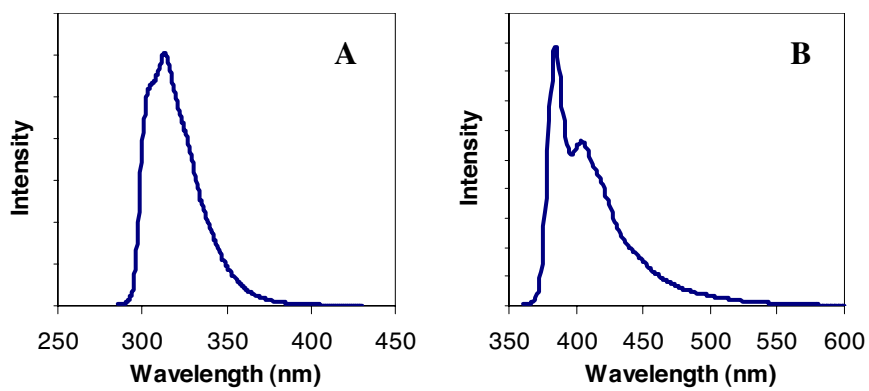


Fig. S3. Fluorescence spectra of monomers in methanol. (A) Diacetylene monomer 2 excited at 275 nm. (B) Terphenyl monomer 3 excited at 350 nm.

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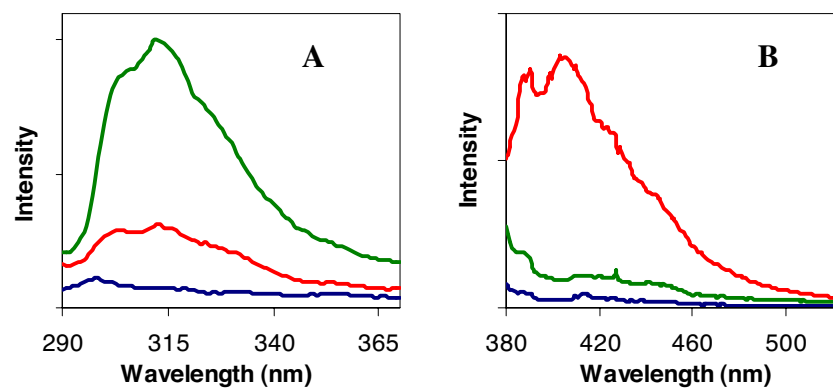


Fig. S4. Combined fluorescence spectra for SAMs and linked SAM from 2 on SiO₂ spheres suspended in methanol. (A) Fluorescence from excitation at 275 nm. Bare SiO₂ spheres (blue), SAM from 2 (green) linked SAM from 2 (red). (B) Fluorescence from excitation at 370 nm. Bare SiO₂ spheres (blue), SAM from 2 (green), linked SAM from 2 (red). Peak heights were normalized to the 315-nm emission of the SAM from 2.

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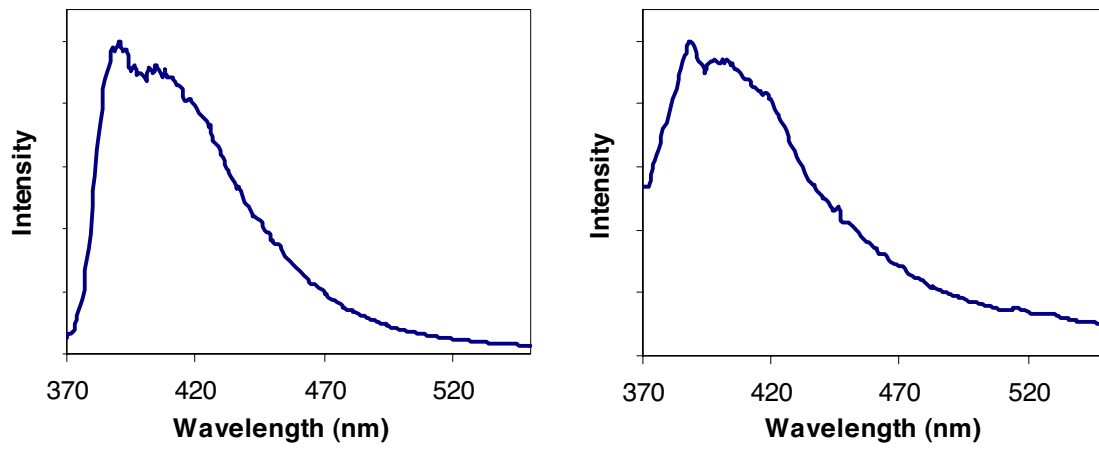


Fig. S5. Fluorescence spectra of SAMs and C³M from 3. (A) Fluorescence spectrum for SAM from 3 on SiO₂ spheres at 350-nm excitation. (B) Fluorescence spectrum for linked SAM from 3 on SiO₂ spheres at 350-nm excitation

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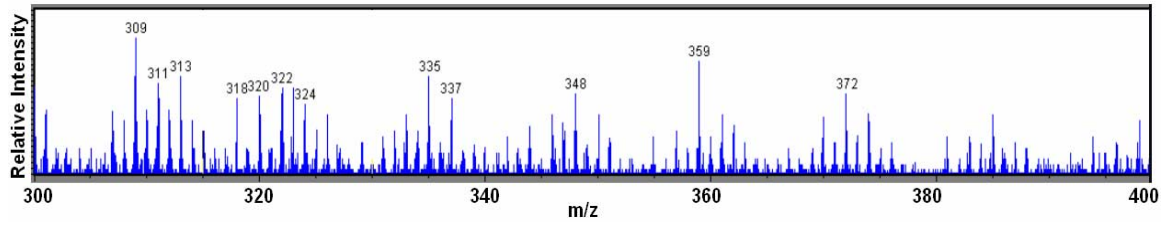


Fig. S6. A representative secondary ion mass spectrum of linked SAM from 2 on its growth substrate (Si wafer with 300-nm thermal SiO₂).

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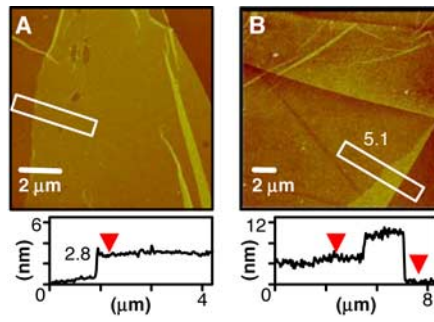


Fig. 57. Source drain current-gate voltage characteristics of a representative back-gate-linked SAM from 2 device (A) and polymer electrolyte gate-linked SAM from 2 device (B). *Insets* show schematic illustrations of cross section and optical image of device.

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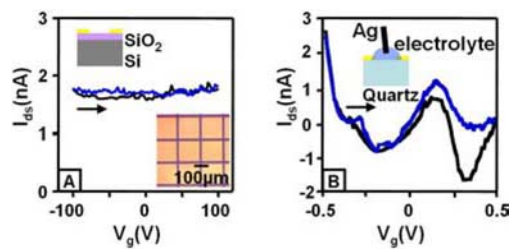


Fig. S8. AFM images of linked SAMs. (A) AFM image and step height of a linked SAM from 2 transferred to a flat Si wafer with 300-nm thermal SiO₂. The graph shows an averaged line cut, revealing a step height of ≈ 2.8 nm. (B) AFM image and step height of a linked SAM from 3 transferred to a flat Si wafer with 300-nm thermal SiO₂. The graph shows an averaged line cut, revealing a step height of ≈ 5.1 nm.

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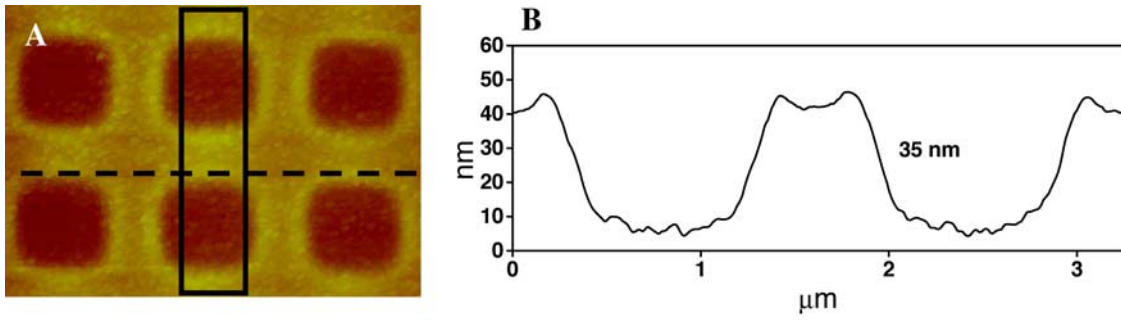
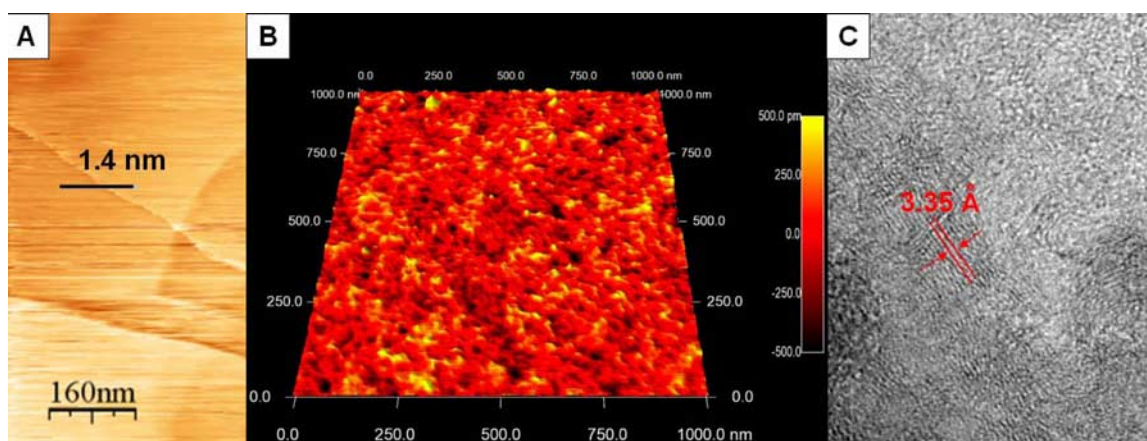


Fig. 59. Atomic force microscope (AFM) characterization of structured growth substrate. (A) Tapping mode AFM image of patterned substrate. (B) An averaged line cut from A, revealing a relief depth of 35 nm.

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AQ: F Fig. S10. ●●●. (A) A STM image of transferred linked SAM from **1** on a freshly cleaved, highly oriented pyrolytic graphite surface. The cross-sectional height is ≈ 1.4 nm. (B) An AFM image of linked SAM from **1** on the growth substrate (Si wafer with 300-nm thermal oxide). The AFM tip radius = 2 nm. The rms of C³M **1** is 0.17 nm, nearly identical to that of bare SiO₂ surface. (C) A TEM image of transferred linked SAM from **1** on a holey carbon TEM grid under a low-dose condition, showing what appear to be strands of polymers separated by a distance of ≈ 3.35 Å.

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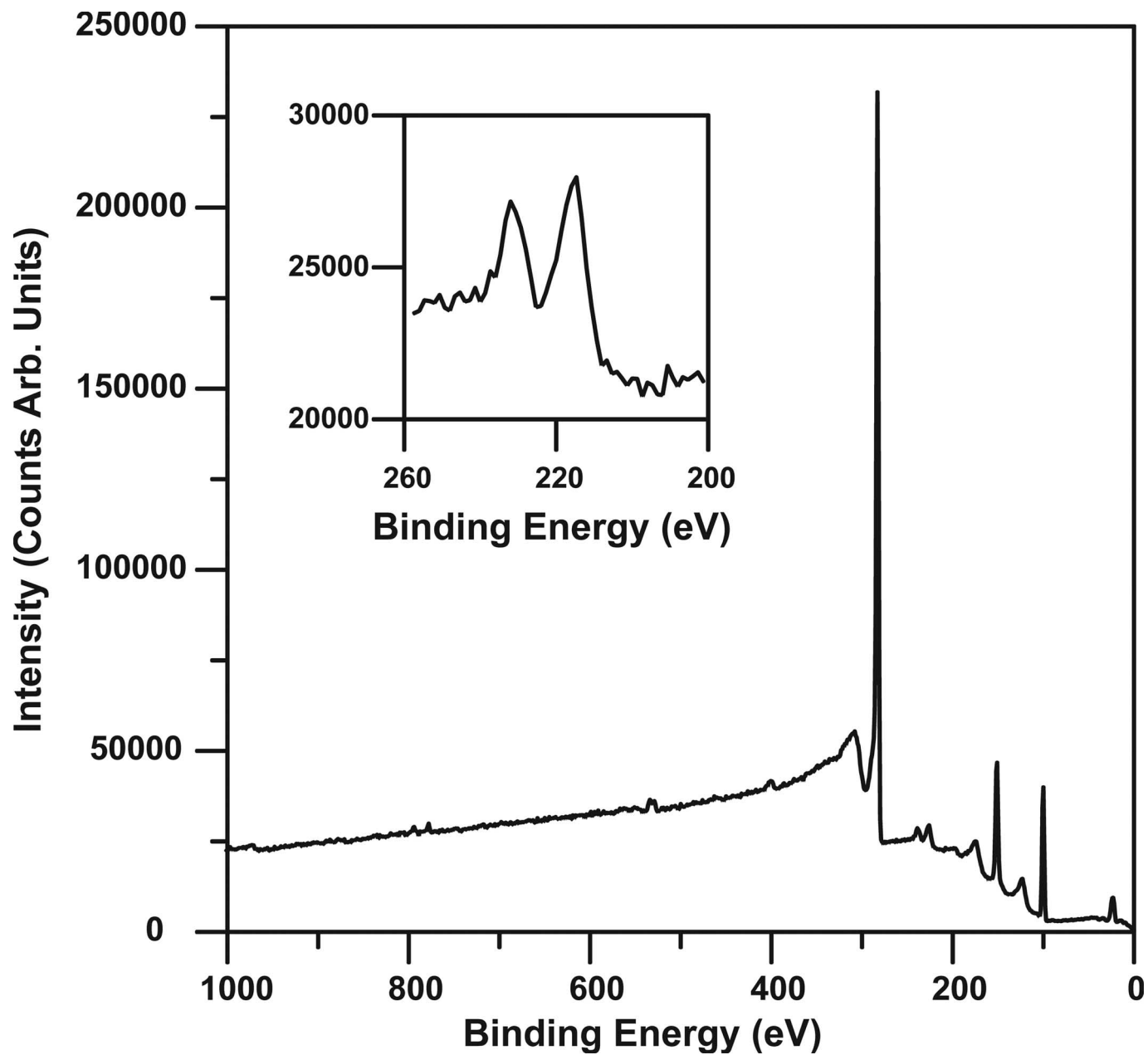


Fig. S11. XPS spectra of a C³M 1 on a Si wafer with a 300-nm thermal SiO₂ layer. *Inset* shows Mo 3d peaks.

Sf11

Table S1. Contact angle measurements for SAMs and linked SAM from 1, 2, and 3 on SiO₂, silicon nitride, and quartz wafers

Support	SAM 1	Linked SAM 1	SAM 2	Linked SAM 2	SAM 3	Linked SAM 3
Silicon oxide	74 (1)	69 (2)	75 (1)	64 (2)	80 (1)	59 (1)
Silicon nitride	74 (2)	70 (2)	77 (1)	64 (2)	80 (1)	62 (1)
Quartz	74 (2)	69 (1)	76 (2)	65 (3)	86 (2)	56 (3)

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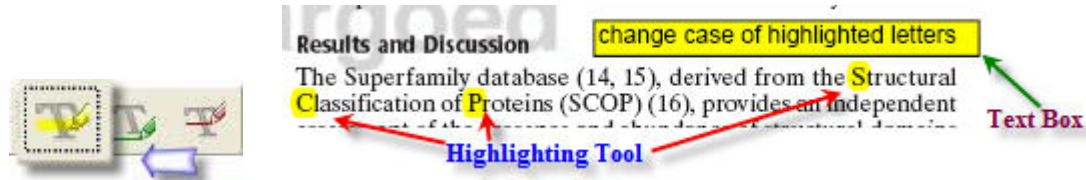
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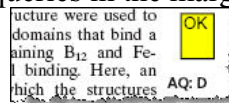
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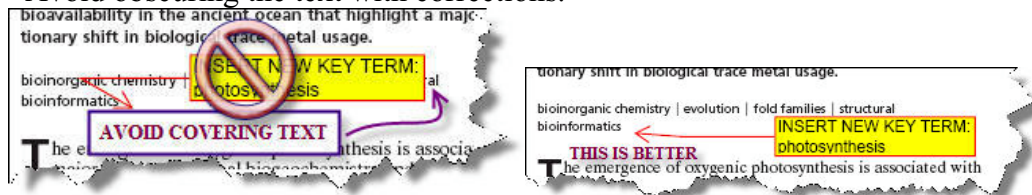
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^	LEFT OUT, INSERT	u Your proof. ^
#	INSERT SPACE	# Yourproof. ^
9	TURN INVERTED LETTER	Your p ^o oof. ^
X	BROKEN LETTER	X Your pr ^o of.
^{vv} eq#	EVEN SPACE	eq# A good proof.
○	CLOSE UP: NO SPACE	Your pro ^o gf.
tr	TRANSPOSE	tr A proof ^o good
wf	WRONG FONT	wf Your proof.
lc	LOWER CASE	lc Your proof.
≡ caps	CAPITALS	Your proof. caps Your proof.
ital	ITALIC	Your proof. ital Your proof.
rom	ROMAN, NON ITALIC	rom Your proof.
bf	BOLD FACE	Your proof. bf Your proof.
..... stet	LET IT STAND	Your proof. stet Your proof.
out sc.	DELETE, SEE COPY	out sc. She Our proof. ^
spell out	SPELL OUT	spell out Queen (Eliz.)
#	START PARAGRAPH	# read. [Your
no #	NO PARAGRAPH: RUN IN	no # marked. → # Your proof.
└	LOWER	└ [Your proof.]

MARK	EXPLANATION	EXAMPLE
┐	RAISE	┐ [Your proof.]
┌	MOVE LEFT	┌ Your proof.
└	MOVE RIGHT	└ Your proof.
	ALIGN TYPE	┌ Three dogs. └ Two horses.
==	STRAIGHTEN LINE	== Your p ^o oof.
⊙	INSERT PERIOD	⊙ Your proof. ^
;/	INSERT COMMA	;/ Your proof. ^
:/	INSERT COLON	:/ Your proof. ^
;/	INSERT SEMICOLON	;/ Your proof. ^
∨	INSERT APOSTROPHE	∨ Your m ^o ans proof. ^
∨∨	INSERT QUOTATION MARKS	∨∨ Marked it proof. ^ ^
=/	INSERT HYPHEN	=/ A proofmark. ^
!	INSERT EXCLAMATION MARK	! Prove it. ^
?	INSERT QUESTION MARK	? Is it right. ^
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